

GaAs INTEGRATED CIRCUIT

μ PG2015TB

L, S-BAND SPDT SWITCH

DESCRIPTION

The μ PG2015TB is a GaAs MMIC for L, S-band SPDT (Single Pole Double Throw) switch which were developed for mobile phone and another L, S-band application.

This device can operate frequency from 0.5 GHz to 2.5 GHz, having the low insertion loss and high isolation.

This device is housed in a 6-pin super minimold package. And this package is able to high-density surface mounting.

FEATURES

Supply voltage : VDD = 2.7 to 3.0 V (2.8 V TYP.)

Switch control voltage : V_{cont (H)} = 2.7 to 3.0 V (2.8 V TYP.)

: $V_{cont(L)} = -0.2 \text{ to } +0.2 \text{ V } (0 \text{ V TYP.})$

Low insertion loss
 Lins1 = 0.25 dB TYP. @ f = 0.5 to 1.0 GHz, VDD = 2.8 V, Vcont = 2.8 V/0 V

: LINS2 = 0.30 dB TYP. @ f = 1.0 to 2.0 GHz, $V_{DD} = 2.8 \text{ V}$, $V_{cont} = 2.8 \text{ V}/0 \text{ V}$

: LINS3 = 0.35 dB TYP. @ f = 2.5 GHz, VDD = 2.8 V, Vcont = 2.8 V/0 V

• High isolation : ISL₁ = 27 dB TYP. @ f = 0.5 to 2.0 GHz, $V_{DD} = 2.8$ V, $V_{cont} = 2.8$ V/0 V

: $ISL_2 = 24 \text{ dB TYP.}$ @ f = 2.5 GHz, $V_{DD} = 2.8 \text{ V}$, $V_{cont} = 2.8 \text{ V}/0 \text{ V}$

• Middle power : $P_{in(0.1 dB)} = +27.0 dBm TYP$. @ f = 2.5 GHz, $V_{DD} = 2.8 V$, $V_{cont} = 2.8 V/0 V$

• High-density surface mounting : 6-pin super minimold package $(2.0 \times 1.25 \times 0.9 \text{ mm})$

APPLICATIONS

• L-band digital cellular or cordless telephone

PCS, W-LAN, WLL and BluetoothTM etc.

ORDERING INFORMATION

| Part Number | Package | Marking | Supplying Form |
|--------------|----------------------|---------|---|
| μPG2015TB-E3 | 6-pin super minimold | G3J | Embossed tape 8 mm wide Pin 1, 2, 3 face the perforation side of the tape Qty 3 kpcs/reel |

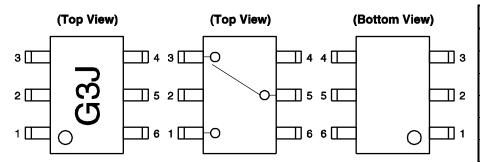
Remark To order evaluation samples, contact your nearby sales office.

Part number for sample order: μPG2015TB-A

Caution: Observe precautions when handling because these devices are sensitive to electrostatic discharge

The information in this document is subject to change without notice. Before using this document, please confirm that this is the latest version.

PIN CONNECTIONS AND INTERNAL BLOCK DIAGRAM



| Pin No. | Pin Name | |
|---------|-----------------|--|
| 1 | OUTPUT1 | |
| 2 | GND | |
| 3 | OUTPUT2 | |
| 4 | Vcont | |
| 5 | INPUT | |
| 6 | V _{DD} | |

TRUTH TABLE

| Vcont | INPUT-OUTPUT1 | INPUT-OUTPUT2 | |
|-------|---------------|---------------|--|
| Low | OFF | ON | |
| High | ON | OFF | |

ABSOLUTE MAXIMUM RATINGS (TA = +25°C, unless otherwise specified)

| Parameter | Symbol | Ratings | Unit |
|-------------------------------|-----------------|-------------|------|
| Supply Voltage | V _{DD} | +6.0 | V |
| Switch Control Voltage | Vcont | +6.0 | V |
| Input Power | Pin | +33 | dBm |
| Operating Ambient Temperature | TA | -45 to +85 | °C |
| Storage Temperature | Tstg | -55 to +150 | °C |

RECOMMENDED OPERATING RANGE (TA = +25°C, unless otherwise specified)

| Parameter | Symbol | MIN. | TYP. | MAX. | Unit |
|----------------------------|-----------------|------|------|------|------|
| Supply Voltage | V _{DD} | 2.7 | 2.8 | 3.0 | V |
| Switch Control Voltage (H) | Vcont(H) | 2.7 | 2.8 | 3.0 | V |
| Switch Control Voltage (L) | Vcont(L) | -0.2 | 0 | 0.2 | V |

ELECTRICAL CHARACTERISTICS

(TA = +25°C, VDD = 2.8 V, Vcont = 2.8 V/0 V, DC cut capacitors = 56 pF, unless otherwise specified)

| Parameter | Symbol | Test Conditions | MIN. | TYP. | MAX. | Unit |
|---------------------------|------------------|--------------------|-------|-------|------|------|
| Insertion Loss 1 | Lins1 | f = 0.5 to 1.0 GHz | - | 0.25 | 0.45 | dB |
| Insertion Loss 2 | LINS2 | f = 1.0 to 2.0 GHz | - | 0.30 | 0.50 | dB |
| Insertion Loss 3 | Linss | f = 2.5 GHz | - | 0.35 | 0.55 | dB |
| Isolation 1 | ISL ₁ | f = 0.5 to 2.0 GHz | 23 | 27 | - | dB |
| Isolation 2 | ISL ₂ | f = 2.5 GHz | 20 | 24 | 7 | dB |
| Input Return Loss | RLin | f = 0.5 to 2.5 GHz | 15 | 20 | - | dB |
| Output Return Loss | RLout | f = 0.5 to 2.5 GHz | 15 | 20 | 1 | dB |
| 0.1 dB Gain Compression | Pin(0.1 dB) | f = 2.0 GHz | +25.5 | +27.0 | _ | dBm |
| Input Power Note | | f = 2.5 GHz | +25.5 | +27.0 | - | dBm |
| Supply Current | loo | | - | 50 | 100 | μΑ |
| Switching Control Current | Icont | | | 4 | 20 | μΑ |
| Switching Control Speed | tsw | | - | 0.3 | 2.0 | μs |

Note P_{in(0.1dB)} is measured the input power level when the insertion loss increases more 0.1 dB than that of linear range.

STANDARD CHARACTERISTICS FOR REFERENCE

(TA = +25°C, VDD = 2.8 V, Vcont = 2.8 V/0 V, DC cut capacitors = 56 pF, unless otherwise specified)

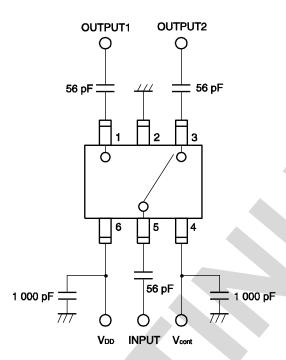
| Parameter | Symbol | Test Conditions | MIN. | TYP. | MAX. | Unit |
|--|-----------|-----------------|------|-------|------|------|
| 1 dB Gain Compression Input Power ^{Note} | Pin(1 dB) | f = 2.0 GHz | - | +30.0 | - | dBm |

Note P_{in(1dB)} is measured the input power level when the insertion loss increases more 1 dB than that of linear range.

Caution This device is used it is necessary to use DC cut capacitors.

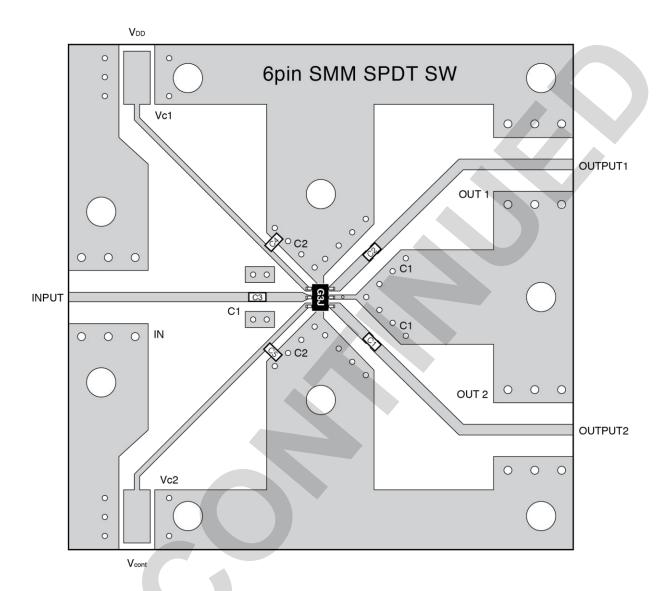
The value of DC cut capacitors should be chosen to accommodate the frequency of operation, bandwidth, switching speed and the condition with actual board of your system. The range of recommended DC cut capacitor value is less than 100 pF.

EVALUATION CIRCUIT (VDD = 2.8 V, Vcont = 2.8 V/0 V, DC cut capacitors = 56 pF)



The application circuits and their parameters are for reference only and are not intended for use in actual design-ins.

ILLUSTRATION OF THE TEST CIRCUIT ASSEMBLED ON EVALUATION BOARD

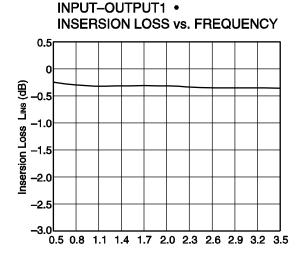


USING THE EVALUATION BOARD

| Symbol | Values |
|------------|----------|
| C1, C2, C3 | 56 pF |
| C4, C5 | 1 000 pF |

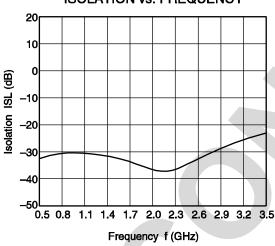
★ TYPICAL CHARACTERISTICS

(TA = +25°C, VDD = 2.8 V, Vcont = 2.8 V/0 V, DC cut capacitors = 56 pF, unless otherwise specified)

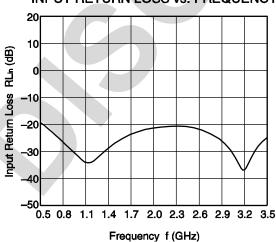




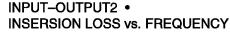
Frequency f (GHz)

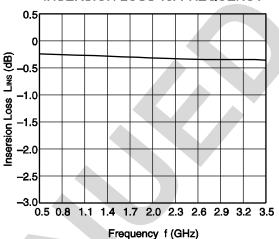


INPUT-OUTPUT1 • INPUT RETURN LOSS vs. FREQUENCY

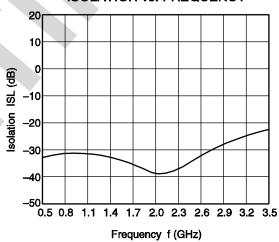


Remark The graphs indicate nominal characteristics.

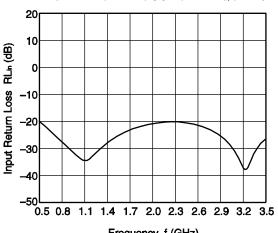




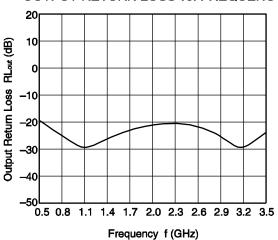
INPUT-OUTPUT2 • **ISOLATION vs. FREQUENCY**



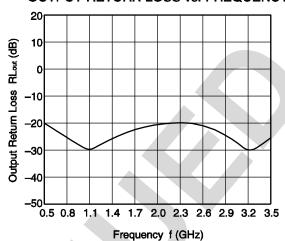
INPUT-OUTPUT2 • INPUT RETURN LOSS vs. FREQUENCY



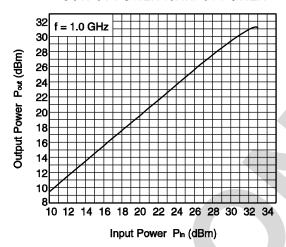
INPUT-OUTPUT1 OUTPUT RETURN LOSS vs. FREQUENCY



INPUT-OUTPUT2 • OUTPUT RETURN LOSS vs. FREQUENCY

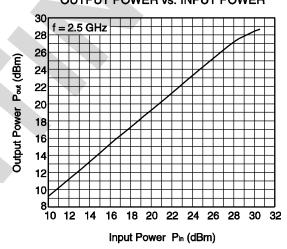


OUTPUT POWER vs. INPUT POWER



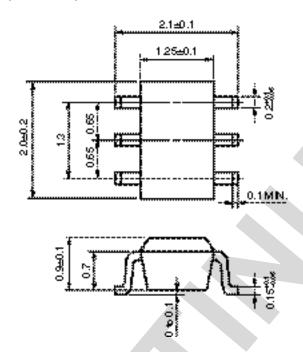
Remark The graphs indicate nominal characteristics.

OUTPUT POWER vs. INPUT POWER



PACKAGE DIMENSIONS

6-PIN SUPER MINIMOLD (UNIT: mm)



RECOMMENDED SOLDERING CONDITIONS

This product should be soldered and mounted under the following recommended conditions. For soldering methods and conditions other than those recommended below, contact your nearby sales office.

| Soldering Method | Soldering Conditions | | Condition Symbol |
|------------------|---|---|------------------|
| Infrared Reflow | Peak temperature (package surface temperature) Time at peak temperature Time at temperature of 220°C or higher Preheating time at 120 to 180°C Maximum number of reflow processes Maximum chlorine content of rosin flux (% mass) | : 260°C or below : 10 seconds or less : 60 seconds or less : 120±30 seconds : 3 times : 0.2%(Wt.) or below | IR260 |
| VPS | Peak temperature (package surface temperature) Time at temperature of 200°C or higher Preheating time at 120 to 150°C Maximum number of reflow processes Maximum chlorine content of rosin flux (% mass) | : 215°C or below : 25 to 40 seconds : 30 to 60 seconds : 3 times : 0.2%(Wt.) or below | VP215 |
| Wave Soldering | Peak temperature (molten solder temperature) Time at peak temperature Preheating temperature (package surface temperature) Maximum number of flow processes Maximum chlorine content of rosin flux (% mass) | : 260°C or below : 10 seconds or less : 120°C or below : 1 time : 0.2%(Wt.) or below | WS260 |
| Partial Heating | Peak temperature (pin temperature) Soldering time (per side of device) Maximum chlorine content of rosin flux (% mass) | : 350°C or below : 3 seconds or less : 0.2%(Wt.) or below | HS350 |

Caution Do not use different soldering methods together (except for partial heating).

Caution

GaAs Products

This product uses gallium arsenide (GaAs).

GaAs vapor and powder are hazardous to human health if inhaled or ingested, so please observe the following points.

- Follow related laws and ordinances when disposing of the product. If there are no applicable laws and/or ordinances, dispose of the product as recommended below.
 - Commission a disposal company able to (with a license to) collect, transport and dispose of materials that contain arsenic and other such industrial waste materials.
- 2. Exclude the product from general industrial waste and household garbage, and ensure that the product is controlled (as industrial waste subject to special control) up until final disposal.
- Do not burn, destroy, cut, crush, or chemically dissolve the product.
- Do not lick the product or in any way allow it to enter the mouth.

